

MAXIM

Quad SPST CMOS Analog Switches

General Description

Maxim's MAX332, DG202 and DG212 are normally open, quad single-pole-single-throw (SPST) analog switches. These CMOS switches can be continuously operated with power supplies ranging from $\pm 4.5\text{V}$ to $\pm 18\text{V}$. Maxim guarantees that the MAX332 and DG202/212 will not latch up if their power supplies are disconnected with input signals still connected.

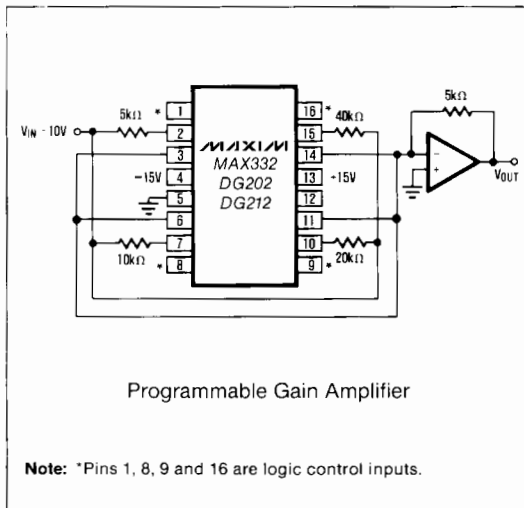
The MAX332 and DG202/DG212 are similar to the DG201 and DG211 except for inverted control inputs. All devices have guaranteed break-before-make switching as well as essentially constant on resistance over the analog signal range. All switches conduct current in either direction and add no offset to the output signal.

Compared to the original manufacturers products, Maxim's MAX332 and DG202/DG212 consume very little power, making them ideally suited for portable applications. Maxim has also eliminated the need for the third logic power supply (V_L), required when operating the original manufacturer's DG212, without sacrificing compatibility.

Applications

Analog Multiplexers
Programmable Gain Amplifiers
Communications Systems
Sample/Holds
Automatic Test Equipment
PBX, PABX

Typical Operating Circuit



Features

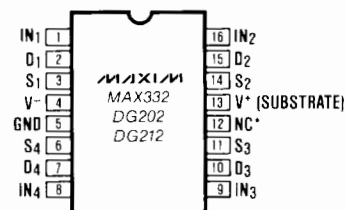
- ◆ Improved 2nd Source! (See pages 3 and 5 for "MAXIM Advantage™")
- ◆ Guaranteed $\pm 4.5\text{V}$ to $\pm 18\text{V}$ Operation
- ◆ No V_L Supply Required
- ◆ Non-Latching with Supplies Turned-off and Input Signals Present
- ◆ CMOS and TTL Logic Compatible
- ◆ Monolithic, Low Power CMOS Design

Ordering Information

PART	TEMP. RANGE	PACKAGE
MAX332MJE	-55°C to $+125^\circ\text{C}$	16 Lead CERDIP
DG202C/D	0°C to $+70^\circ\text{C}$	Dice
DG202CJ	0°C to $+70^\circ\text{C}$	16 Lead Plastic DIP
DG202CSE	0°C to $+70^\circ\text{C}$	16 Lead Small Outline
DG202CK	0°C to $+70^\circ\text{C}$	16 Lead CERDIP
DG202BSE	-25°C to $+85^\circ\text{C}$	16 Lead Small Outline
DG202BK	-25°C to $+85^\circ\text{C}$	16 Lead CERDIP
DG202AK	-55°C to $+125^\circ\text{C}$	16 Lead CERDIP
DG212C/D	0°C to $+70^\circ\text{C}$	Dice
DG212CJ	0°C to $+70^\circ\text{C}$	16 Lead Plastic DIP
DG212CSE	0°C to $+70^\circ\text{C}$	16 Lead Small Outline

Pin Configuration

Top View



LOGIC	SWITCH
0	OFF
1	ON

Note: *Pin 12 can be left open or connected to a logic supply voltage.

MAXIM

Maxim Integrated Products 1

Call toll free 1-800-998-8800 for free samples or literature.

MAX332/DG202/DG212

Quad SPST CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS (DG212)

V^+ to V^-	40V
V_{IN} to Ground	V^- , V^+
V_L to Ground	-0.3V, 25V
V_S or V_D to V^+	0, -40V
V_S or V_D to V^-	0, 40V
V^+ to Ground	25V
V^- to Ground	-25V
Current, Any Terminal Except S or D	30mA
Continuous Current, S or D	20mA
Peak Current, S or D (Pulsed at 1msec, 10% duty cycle max)	70mA

Storage Temperature	-65°C to +125°C
Operating Temperature	0°C to +70°C
Power Dissipation (Note 1)	
16 Pin Plastic DIP (Note 2)	470mW
16 Pin Small Outline (SE) (Note 3)	400mW

Note 1: Device mounted with all leads soldered to PC board.

Note 2: Derate 6.5mW/°C above +25°C.

Note 3: Derate 7mW/°C above +25°C.

Stresses listed under "Absolute Maximum Ratings" may be applied (one at a time) to devices without resulting in permanent damage. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (DG212)

($V^+ = +15V$, $V^- = -15V$, GND = 0V, $T_A = +25^\circ C$, unless otherwise noted)

	PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
				MIN (Note 4)	TYP (Note 5)	MAX	
SWITCH	Analog Signal Range	V_{ANALOG}		-15		15	V
	Drain-Source ON Resistance	$r_{DS(on)}$	$V_D = \pm 10V$, $V_{IN} = 2.4V$, $I_S = 1mA$		115	175	Ω
	Source OFF Leakage Current	$I_{S(off)}$	$V_{IN} = 0.8V$ $V_S = 14V$, $V_D = -14V$ $V_S = -14V$, $V_D = 14V$		0.01 -5.0	5.0	nA
	Drain OFF Leakage Current	$I_{D(off)}$	$V_{IN} = 0.8V$ $V_S = 14V$, $V_D = -14V$ $V_S = -14V$, $V_D = 14V$		0.01 -5.0	5.0	
	Drain ON Leakage Current (Note 6)	$I_{D(on)}$	$V_S = V_D = 14V$, $V_{IN} = 2.4V$ $V_S = V_D = -14V$, $V_{IN} = 2.4V$		0.1 -0.15	5.0	
	Input Current With Input Voltage High	I_{INH}	$V_{IN} = 2.4V$ $V_{IN} = 15V$	-1.0	-0.0004		μA
INPUT	Input Current With Input Voltage Low	I_{INL}	$V_{IN} = 0V$	-1.0	-0.0004	1.0	
DYNAMIC	Turn-ON Time	t_{on}	See Switching Time Test Circuit $V_S = 2V$, $R_L = 1k\Omega$, $C_L = 35pF$		460	1000	ns
	Turn-OFF Time	t_{off1}			360	500	
		t_{off2}			450		
	Source OFF Capacitance	$C_{S(off)}$	$V_S = 0V$, $V_{IN} = 0V$, $f = 1MHz$		5		pF
	Drain OFF Capacitance	$C_{D(off)}$	$V_D = 0V$, $V_{IN} = 0V$, $f = 1MHz$		5		
	Channel ON Capacitance	$C_{D+S(on)}$	$V_D = V_S = 5V$, $V_{IN} = 0V$, $f = 1MHz$		16		
	OFF Isolation (Note 7)	OIRR	$V_{IN} = 0V$, $R_L = 1k\Omega$, $C_L = 15pF$, $V_S = 1VRMS$, $f = 100kHz$		70		dB
SUPPLY	Crosstalk (Channel to Channel)	CCRR			90		
	Positive Supply Current	I^+	$V_{IN} = 0V$ and $2.4V$		0.35	0.48	mA
	Negative Supply Current	I^-			0.30	0.48	
	Logic Supply Current	I_L			0.5	1.2	

Note 4: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this data sheet.

Note 5: Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Note 6: $I_{D(on)}$ is leakage from driver into "ON" switch.

Note 7: OFF Isolation = $20 \log \frac{V_S}{V_D}$, V_S = input to OFF switch, V_D = output.

The electrical characteristics above are a reproduction of a portion of Siliconix's copyrighted 1985 data book. This information does not constitute any representation by Maxim that Siliconix's products will perform in accordance with these specifications. The "Electrical Characteristics Table" along with descriptive excerpts from the original manufacturer's data sheet have been included in this data sheet solely for comparative purposes.



Quad SPST CMOS Analog Switches

- ◆ Significantly Reduced Power Consumption
- ◆ Third (Logic) Supply Not Required
- ◆ Fault Protected

ABSOLUTE MAXIMUM RATINGS (DG212): This device conforms to the Absolute Maximum Ratings on the adjacent page.

ELECTRICAL CHARACTERISTICS (DG212): Specifications below satisfy or exceed all “tested” parameters on adjacent page.

($V^+ = +15V$, $V^- = -15V$, $GND = 0V$, $T_A = +25^\circ C$, unless otherwise noted)

	PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
				MIN (Note 4)	TYP (Note 5)	MAX	
SWITCH	Analog Signal Range	V_{ANALOG}		-15		15	V
	Drain-Source ON Resistance	$r_{DS(on)}$	$V_D = \pm 10V$, $V_{IN} = 2.4V$, $I_S = 1mA$		115	175	Ω
	Source OFF Leakage Current	$I_{S(off)}$	$V_{IN} = 0.8V$ $V_S = 14V$, $V_D = -14V$ $V_S = -14V$, $V_D = 14V$		0.01 -5.0	5.0 -0.02	nA
	Drain OFF Leakage Current	$I_{D(off)}$	$V_{IN} = 0.8V$ $V_S = 14V$, $V_D = -14V$ $V_S = -14V$, $V_D = 14V$		0.01 -5.0	5.0 -0.02	
	Drain ON Leakage Current (Note 6)	$I_{D(on)}$	$V_S = V_D = 14V$, $V_{IN} = 2.4V$		0.1	5.0	
			$V_S = V_D = -14V$, $V_{IN} = 2.4V$	-5.0	-0.15		
INPUT	Input Current With Input Voltage High	I_{INH}	$V_{IN} = 2.4V$ $V_{IN} = 15V$	-1.0	-0.0004 0.003	1.0	μA
	Input Current With Input Voltage Low	I_{INL}	$V_{IN} = 0V$	-1.0	-0.0004		
DYNAMIC	Turn-ON Time	t_{on}	See Switching Time Test Circuit $V_S = 2V$, $R_L = 1k\Omega$, $C_L = 35pF$		460	1000	ns
	Turn-OFF Time	t_{off1}			360	500	
		t_{off2}			450		
	Source OFF Capacitance	$C_{S(off)}$	$V_S = 0V$, $V_{IN} = 0V$, $f = 1MHz$		5		pF
	Drain OFF Capacitance	$C_{D(off)}$	$V_D = 0V$, $V_{IN} = 0V$, $f = 1MHz$		5		
	Channel ON Capacitance	$C_{D+S(on)}$	$V_D = V_S = 0V$, $V_{IN} = 5V$, $f = 1MHz$		16		
	OFF Isolation (Note 8)	OIRR	$V_{IN} = 0V$, $R_L = 1k\Omega$, $C_L = 15pF$, $V_S = 1VRMS$, $f = 100kHz$		70		dB
	Crosstalk (Channel to Channel)	CCRR			90		
SUPPLY	Positive Supply Current	I^+	$V_{IN} = 0V$ and $2.4V$		0.02	0.1	mA
	Negative Supply Current	I^-			0.00001	0.1	
	Logic Supply Current	I_L			0.0	0.0	
	Power Supply Range for Continuous Operation	V_{OP}		± 4.5		± 18	V

Note 8: Electrical characteristics, such as ON Resistance, will change when power supplies, other than $\pm 15V$, are used.

MAX332/DG202/DG212

Quad SPST CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS (DG202)

Voltages Referenced to V ⁻	
V ⁺	44V
GND	25V
Digital Inputs (Note 1), V _S , V _D	-2V, to (V ⁺ +2V) or 20mA, whichever occurs first
Current, Any Terminal Except S or D	30mA
Continuous Current, S or D	20mA
Peak Current, S or D (Pulsed at 1msec, 10% duty cycle max.)	70mA
Operating Temperature	
DG202 (A Suffix)	-55°C to +125°C
(B Suffix)	-25°C to +85°C
(C Suffix)	0°C to +70°C
MAX332MJE	-55°C to +125°C

Storage Temperature	-65°C to +150°C
Power Dissipation (Note 2)	
16 Pin CERDIP (Note 3)	900mW
16 Pin Plastic DIP (Note 4)	470mW
16 Pin Small Outline (SE) (Note 5)	400mW

Note 1: Signals on S_X, D_X, or I_{NX} exceeding V⁺ or V⁻ on Maxim's MAX332 and DG202 will be clamped by internal diodes, and are also internally current limited to 25mA.

Note 2: Device mounted with all leads soldered to PC board.

Note 3: Derate 12mW/°C above +75°C.

Note 4: Derate 6.5mW/°C above +25°C.

Note 5: Derate 7mW/°C above +25°C.

Stresses listed under "Absolute Maximum Ratings" may be applied (one at a time) to devices without resulting in permanent damage. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (DG202)

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = +25°C, unless otherwise noted)

	PARAMETER	SYMBOL	TEST CONDITIONS		LIMITS						UNITS
					DG202A			DG202B,C			
					MIN (Note 6)	TYP (Note 7)	MAX	MIN (Note 6)	TYP (Note 7)	MAX	
SWITCH	Analog Signal Range	V _{ANALOG}			-15		15	-15		15	V
	Drain-Source ON Resistance	r _{DS (on)}	V _D = ±10V, V _{IN} = 2.4V, I _S = 1mA			115	175		115	200	Ω
	Source OFF Leakage Current	I _{S (off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V		0.01	1.0		0.01	5.0	nA
	Drain OFF Leakage Current	I _{D (off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V		0.01	1.0		0.01	5.0	
	Drain ON Leakage Current (Note 8)	I _{D (on)}	V _S = -14V, V _{IN} = 2.4V V _D = 14V, V _{IN} = 2.4V		-1.0	-0.15		-5.0	-0.15		
INPUT	Input Current With Input Voltage High	I _{INH}	V _{IN} = 2.4V V _{IN} = 15V		-1.0	-0.0004		-1.0	-0.0004		μA
	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V		-1.0	-0.0004		-1.0	-0.0004		
	DYNAMIC	Turn-ON Time	t _{on}	See Switching Time Test Circuit			480	600		480	600
Turn-OFF Time		t _{off}				370	450		370	450	
Charge Injection		Q	C _L = 1000pF, V _{GEN} = 0V, R _{GEN} = 0Ω			20			20		pC
Source OFF Capacitance		C _{S (off)}	V _S = 0V, V _{IN} = 0V			5			5		pF
Drain OFF Capacitance		C _{D (off)}	f = 140kHz			5			5		
Channel ON Capacitance		C _{D (on)} + C _{S (on)}			V _D = V _S = 0V, V _{IN} = 5V			16			
OFF Isolation			V _{IN} = 0V, Z _L = 75kΩ			70			70		dB
Crosstalk (Channel to Channel)		V _S = 2.0V, f = 100kHz			90			90			
SUP-PLY	Positive Supply Current	I ⁺	All Channels ON or OFF			0.9	2		0.9	2	mA
	Negative Supply Current	I ⁻	All Channels ON or OFF		-1	-0.3		-1	-0.3		

Note 6: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this data sheet.

Note 7: Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Note 8: I_{D(on)} is leakage from driver into "ON" switch.

The electrical characteristics above are a reproduction of a portion of Siliconix's copyrighted 1985 data book. This information does not constitute any representation by Maxim that Siliconix's products will perform in accordance with these specifications. The "Electrical Characteristics Table" along with descriptive excerpts from the original manufacturer's data sheet have been included in this data sheet solely for comparative purposes.



Quad SPST CMOS Analog Switches

- ◆ Significantly Reduced Power Consumption
- ◆ Lower Input Current Over Temperature
- ◆ No Input Current Spike

ABSOLUTE MAXIMUM RATINGS (MAX332, DG202): This device conforms to the Absolute Maximum Ratings on the adjacent page.

ELECTRICAL CHARACTERISTICS (MAX332, DG202): Specifications below satisfy or exceed all "tested" parameters on adjacent page.

($V^+ = +15V$, $V^- = -15V$, $GND = 0V$, $T_A = +25^\circ C$, unless otherwise noted)

	PARAMETER	SYMBOL	TEST CONDITIONS		LIMITS						UNITS
					MAX332/DG202A			DG202B,C			
					MIN (Note 6)	TYP (Note 7)	MAX	MIN (Note 6)	TYP (Note 7)	MAX	
SWITCH	Analog Signal Range	V _{ANALOG}			-15		15	-15		15	V
	Drain-Source ON Resistance (Note 9)	r _{DS (on)}	V _D = ±10V, V _{IN} = 2.4V, I _S = 1mA			115	175		115	200	Ω
	Source OFF Leakage Current	I _{S (off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V		0.01	1.0		0.01	5.0	nA
	Drain OFF Leakage Current	I _{D (off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V		0.01	1.0		0.01	5.0	
	Drain ON Leakage Current (Note 8)	I _{D (on)}	V _S = -14V, V _{IN} = 2.4V V _D = 14V, V _{IN} = 2.4V		0.1	1.0		0.1	5.0		
INPUT	Input Current With Input Voltage High	I _{INH}	V _{IN} = 2.4V V _{IN} = 15V		-1.0	-0.0004		-1.0	-0.0004		μA
	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V		-1.0	-0.0004		-1.0	-0.0004		
DYNAMIC	Turn-ON Time	t _{on}	See Switching Time Test Circuit		480	600		480	600		ns
	Turn-OFF Time	t _{off1}			370	450		370	450		
	Charge Injection	Q	C _L = 1000pF, V _{GEN} = 0V, R _{GEN} = 0Ω		20			20		pC	
	Source OFF Capacitance	C _{S (off)}	V _S = 0V, V _{IN} = 0V f = 140kHz		5			5		pF	
	Drain OFF Capacitance	C _{D (off)}			5			5			
	Channel ON Capacitance	C _{D (on)} + C _{S (on)}			16			16			
	OFF Isolation		V _{IN} = 0V, Z _L = 75kΩ		70			70		dB	
Crosstalk (Channel to Channel)		V _S = 2.0V, f = 100kHz		90			90				
SUPPLY	Positive Supply Current	I ⁺	All Channels ON or OFF		0.02	0.1		0.02	0.1	mA	
	Negative Supply Current	I ⁻	All Channels ON or OFF		-0.1	-0.01		-0.1	-0.01		
	Power Supply Range for Continuous Operation	V _{OP}			±4.5		±18	±4.5		±18	V

Note 6: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this data sheet.

Note 7: Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Note 8: $I_{D(on)}$ is leakage from driver into "ON" switch.

Note 9: Electrical characteristics, such as ON Resistance, will change when power supplies other than $\pm 15V$, are used.

MAX332/DG202/DG212

MAX332/DG202/DG212

($V^+ = +15V$, $V^- = -15V$, GND = 0V, T_A = Full Operating Temperature Range)

Note 10: $I_{D(ON)}$ is leakage from driver into "ON" switch.

Switching Time Test Circuit

V_O is the steady state output with switch on. Feed-through via gate capacitance may result in spikes at leading and trailing edge of output waveform.

6



Quad SPST CMOS Analog Switches

ELECTRICAL CHARACTERISTICS (MAX332, DG202):

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = full operating temperature range)

	PARAMETER	SYMBOL	TEST CONDITIONS		LIMITS						UNITS
					MAX332/DG202A			DG202B,C			
					MIN	TYP	MAX	MIN	TYP	MAX	
					(Note 6)	(Note 7)		(Note 6)	(Note 7)		
SWITCH	Analog Signal Range	V _{ANALOG}			-15		15	-15		15	V
	Drain-Source ON Resistance (Note 11)	r _{DS(on)}	V _D = ±10V, V _{IN} = 2.4V, I _S = 1mA		250			250			Ω
	Source OFF Leakage Current	I _{S(off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V	100			100			nA
	Drain OFF Leakage Current	I _{D(off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V V _S = -14V, V _D = 14V	100			100			
				-100			-100				
				100			100				
Drain ON Leakage Current (Note 10)	I _{D(on)}	V _S = -14V, V _{IN} = 2.4V V _D = 14V, V _{IN} = 2.4V		200			200				
INPUT	Input Current With Input Voltage High	I _{INH}	V _{IN} = 2.4V V _{IN} = 15V		-1.0			-1.0			μA
	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V		-1.0			-1.0			

Note 10: I_{D(on)} is leakage from driver into "ON" switch.

Note 11: Electrical characteristics, such as ON Resistance, will change when power supplies other than ±15V, are used.

Protecting Against Fault Conditions

Fault conditions occur when power supplies are turned off when input signals are still present or when over voltages occur at the inputs during normal operation. In either case, source-to-body diodes can be forward biased and conduct current from the signal source. If this current is required to be kept to low (μA) levels then the addition of external protection diodes is recommended.

To provide protection for over-voltages up to 20V above the supplies, a 1N4001 or 1N914 type diode should be placed in series with the positive and negative supplies as shown in Fig. 1. The addition of these diodes will reduce the analog signal range to 1 volt below the positive supply and 1 volt above the negative supply.

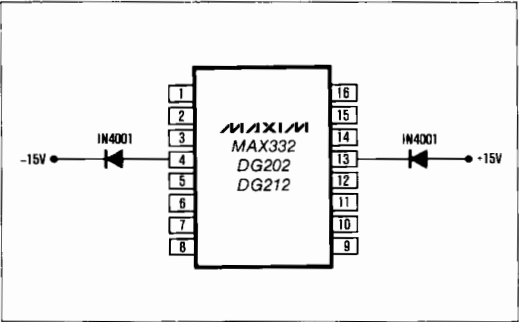
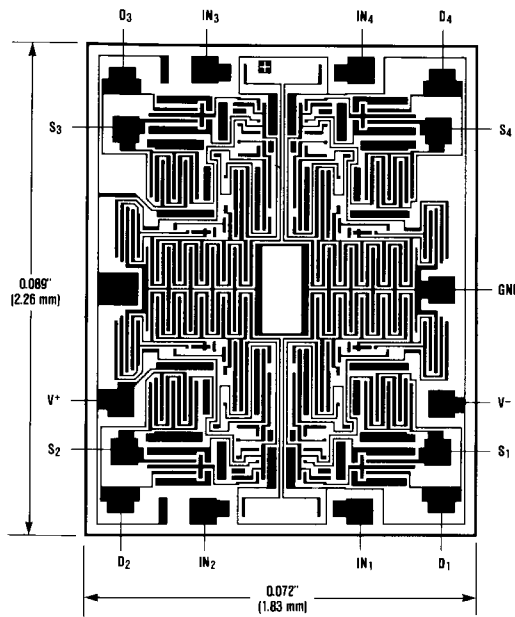


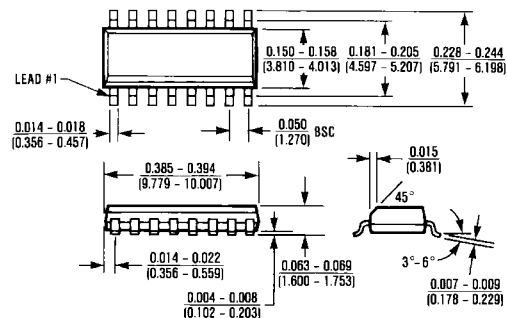
Figure 1. Protection Against Fault Conditions

Quad SPST CMOS Analog Switches

Chip Topography

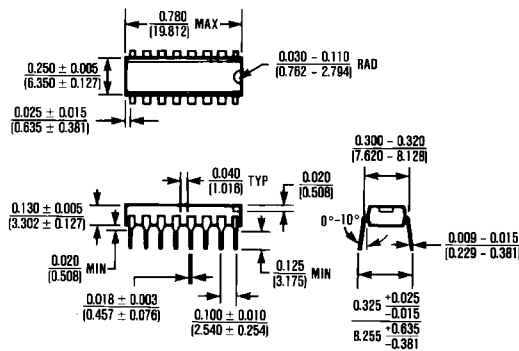


Package Information



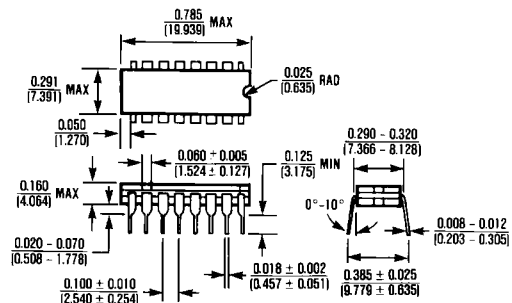
16 Lead Small Outline (SE)

$\theta_{JA} = 110^{\circ}\text{C/W}$
 $\theta_{JC} = 60^{\circ}\text{C/W}$



16 Lead Plastic DIP

$\theta_{JA} = 135^{\circ}\text{C/W}$
 $\theta_{JC} = 65^{\circ}\text{C/W}$



16 Lead CERPDP

$\theta_{JA} = 100^{\circ}\text{C/W}$
 $\theta_{JC} = 60^{\circ}\text{C/W}$

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

8 Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 (408) 737-7600

© 1995 Maxim Integrated Products

Printed USA

MAXIM is a registered trademark of Maxim Integrated Products.